

140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013

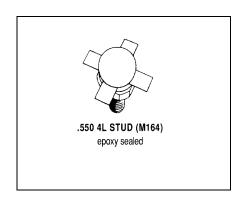
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#### **MS1280**

## RF & MICROWAVE TRANSISTORS TV/LINEAR APPLICATIONS

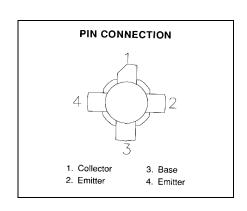
#### **Features**

- 170-230 MHz
- 28 VOLTS
- IMD = -53 dBc
- P<sub>OUT</sub> = 20 WATTS
- $G_P = 7.5 \text{ dB MINIMUM}$
- COMMON EMITTER CONFIGURATION



#### **DESCRIPTION:**

The MS1280 is a gold metallized epitaxial silicon NPN transistor designed for high linearity class AB operation. Internal impedance matching and an emitter ballasted die geometry make this devise ideally suited for VHF and Band III television transmitter and transposers.



## ABSOLUTE MAXIMUM RATINGS (Tcase = $25^{\circ}$ C)

Symbol	Parameter	Value	Unit
$V_{\sf CBO}$	Collector-Base Voltage	60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V
$V_{EBO}$	Emitter-Base Voltage	4.0	V
Ic	Device Current	16	Α
P <sub>DISS</sub>	Power Dissipation	150	W
<b>T</b> J	Junction Temperature	+200	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C

## **Thermal Data**

R <sub>TH(J-C)</sub>	Thermal Resistance Junction-case	1.2	°C/W
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# **ELECTRICAL SPECIFICATIONS (Tcase = 25°C) STATIC**

Symbol	Test Conditions			Value		
Symbol			Min.	Тур.	Max.	Unit
BV <sub>CBO</sub>	I <sub>C</sub> = 100mA	I <sub>E</sub> = 0mA	60			V
BV <sub>CER</sub>	I <sub>C</sub> = 100mA	$R_{BE} = 10\Omega$	60			V
BV <sub>CEO</sub>	I <sub>C</sub> = 100mA	$I_B = 0mA$	30			V
BV <sub>EBO</sub>	I <sub>E</sub> = 20mA	$I_C = 0mA$	4.0			V
HFE	V <sub>CE</sub> = 5V	I <sub>C</sub> = 1A	10		120	

#### **DYNAMIC**

Symbol	Test Conditions			Value			
Symbol		rest conditions		Min.	Тур.	Max.	Unit
P <sub>out</sub>	f = 225 MHz	V <sub>CE</sub> = 28W	I <sub>C</sub> = 3.5 mA	20			w
G <sub>P</sub>	f = 225 MHz	V <sub>CE</sub> = 28W	I <sub>C</sub> = 3.5 mA	7.5		8.0	dB
IMD	f = 225 MHz	V <sub>CE</sub> = 28W	I <sub>C</sub> = 3.5 mA		-53		dB
Сов	f =1 MHz	V <sub>CB</sub> = 30V				150	pf

### **IMPEDANCE DATA**

FREQ	$Z_{IN}(\Omega)$	$Z_{CL}(\Omega)$
170 MHz	0.6 + j0.7	5.9 + j3.5
200 MHz	0.55 + j0.8	5.0 + j3.0
230 MHz	0.5 + j0.9	4.2 + j2.8

 $P_{OUT} = 20W$   $V_{CE} = 28V$ 





#### PACKAGE MECHANICAL DATA

